

Notice of References CitedApplication/Control No.
09/904,129Applicant(s)/Patent Under
Reexamination
UEDA, TETSUZOExaminer
Matthew J SongArt Unit
1765

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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NON-PATENT DOCUMENTS

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	U	Puchinger et al. "Gallium Nitride thin layers via a liquid precursor route" (January 2000). Journal of Crystal Growth, Vol 208, Nos 1-4, pp 153-159.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.